

- **Single Chip With Easy Interface Between UART and Serial-Port Connector of IBM™ PC/AT™ and Compatibles**
- **Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-232-F and ITU Recommendation V.28**
- **Designed to Support Data Rates up to 120 kbit/s**
- **Pinout Compatible With SN75C185 and SN75185**
- **ESD Protection to 2 kV on Bus Terminals**
- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB) Packages, and DIPs (N)**

DB, DW, OR N PACKAGE  
(TOP VIEW)

V <sub>DD</sub>	1	20	V <sub>CC</sub>
RA1	2	19	RY1
RA2	3	18	RY2
RA3	4	17	RY3
DY1	5	16	DA1
DY2	6	15	DA2
RA4	7	14	RY4
DY3	8	13	DA3
RA5	9	12	RY5
V <sub>SS</sub>	10	11	GND

## description

The GD75232 combines three drivers and five receivers from TI™ trade-standard SN75188 and SN75189 bipolar quadruple drivers and receivers, respectively. The pinout matches the flow-through design of the SN75C185 to decrease the part count, reduce the board space required, and allow easy interconnection of the UART and serial-port connector of an IBM™ PC/AT™ and compatibles. The bipolar circuits and processing of the GD75232 provide a rugged, low-cost solution for this function at the expense of quiescent power and external passive components relative to the SN75C185.

The GD75232 complies with the requirements of the TIA/EIA-232-F and ITU (formerly CCITT) V.28 standards. These standards are for data interchange between a host computer and a peripheral at signaling rates up to 20 kbit/s. The switching speeds of the GD75232 are fast enough to support rates up to 120 kbit/s with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be expected unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates up to 120 kbit/s, use of ANSI TIA/EIA-423-B (ITU V.10) and TIA/EIA-422-B (ITU V.11) standards is recommended.

The GD75232 is characterized for operation over the temperature range of 0°C to 70°C.



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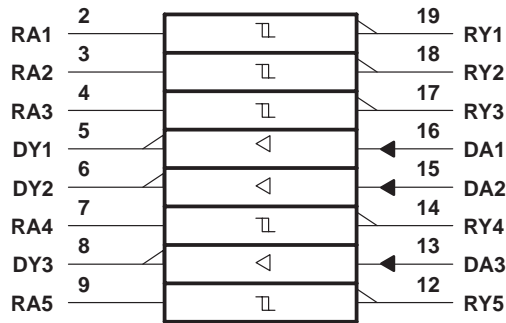
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# GD75232

## MULTIPLE RS-232 DRIVERS AND RECEIVERS

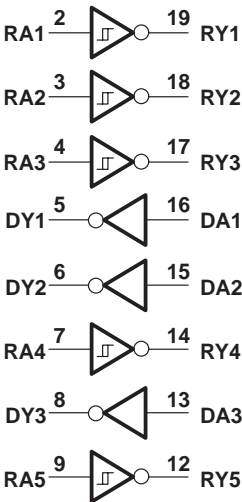
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### logic symbol†

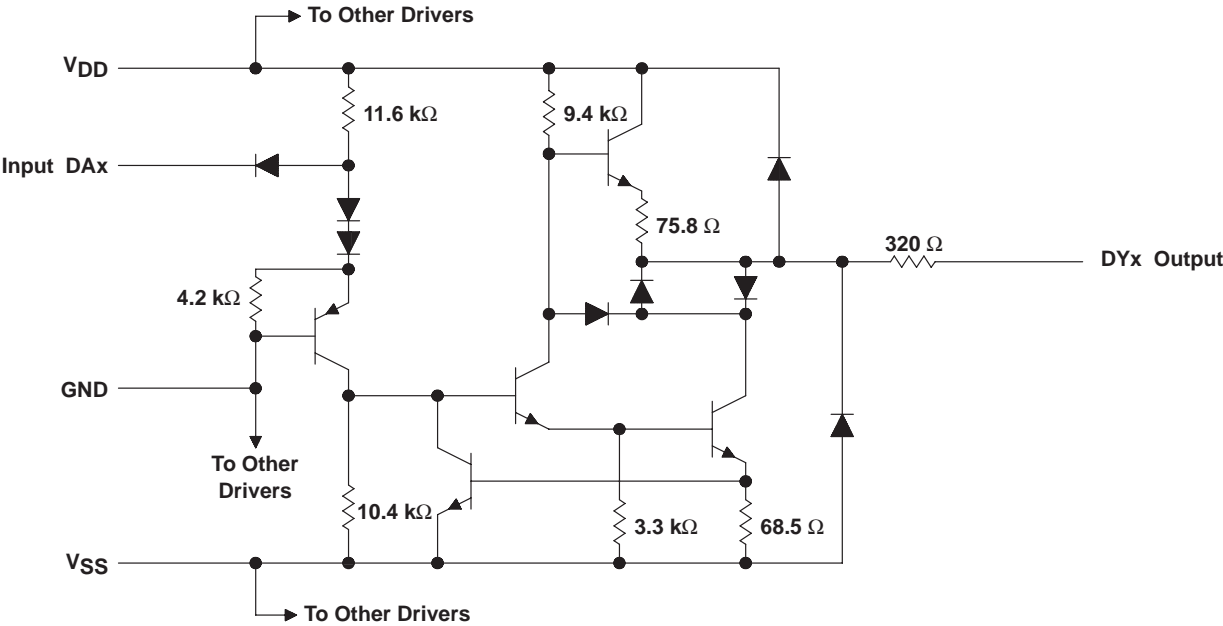


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



### schematic (each driver)



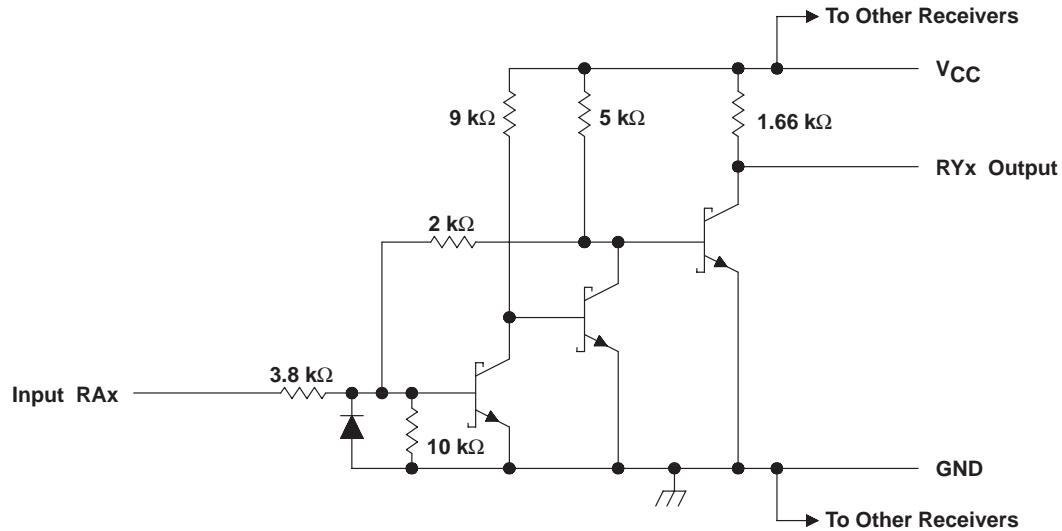
Resistor values shown are nominal.

# GD75232

## MULTIPLE RS-232 DRIVERS AND RECEIVERS

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### schematic (each receiver)



Resistor values shown are nominal.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, $V_{CC}$ (see Note 1)	10 V
Supply voltage, $V_{DD}$ (see Note 1)	15 V
Supply voltage, $V_{SS}$ (see Note 1)	–15 V
Input voltage range, $V_I$ : Driver	–15 V to 7 V
Receiver	–30 V to 30 V
Driver output voltage range, $V_O$	–15 V to 15 V
Receiver low-level output current, $I_{OL}$	20 mA
Package thermal impedance, $\theta_{JA}$ (see Note 2): DB package	115°C/W
DW package	97°C/W
N package	67°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to the network ground terminal.  
2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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## MULTIPLE RS-232 DRIVERS AND RECEIVERS

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### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, $V_{DD}$		7.5	9	15	V
Supply voltage, $V_{SS}$		-7.5	-9	-15	V
Supply voltage, $V_{CC}$		4.5	5	5.5	V
High-level input voltage, $V_{IH}$ (driver only)		1.9			V
Low-level input voltage, $V_{IL}$ (driver only)				0.8	V
High-level output current, $I_{OH}$	Driver			-6	mA
	Receiver			-0.5	
Low-level output current, $I_{OL}$	Driver			6	mA
	Receiver			16	
Operating free-air temperature, $T_A$		0		70	°C

### supply currents over recommended operating free-air temperature range

PARAMETER	TEST CONDITIONS		MIN	MAX	UNIT
$I_{DD}$ Supply current from $V_{DD}$	All inputs at 1.9 V, No load	$V_{DD} = 9\text{ V}, V_{SS} = -9\text{ V}$		15	mA
		$V_{DD} = 12\text{ V}, V_{SS} = -12\text{ V}$		19	
		$V_{DD} = 15\text{ V}, V_{SS} = -15\text{ V}$		25	
	All inputs at 0.8 V, No load	$V_{DD} = 9\text{ V}, V_{SS} = -9\text{ V}$		4.5	mA
		$V_{DD} = 12\text{ V}, V_{SS} = -12\text{ V}$		5.5	
		$V_{DD} = 15\text{ V}, V_{SS} = -15\text{ V}$		9	
$I_{SS}$ Supply current from $V_{SS}$	All inputs at 1.9 V, No load	$V_{DD} = 9\text{ V}, V_{SS} = -9\text{ V}$	-15		mA
		$V_{DD} = 12\text{ V}, V_{SS} = -12\text{ V}$	-19		
		$V_{DD} = 15\text{ V}, V_{SS} = -15\text{ V}$	-25		
	All inputs at 0.8 V, No load	$V_{DD} = 9\text{ V}, V_{SS} = -9\text{ V}$	-3.2		mA
		$V_{DD} = 12\text{ V}, V_{SS} = -12\text{ V}$	-3.2		
		$V_{DD} = 15\text{ V}, V_{SS} = -15\text{ V}$	-3.2		
$I_{CC}$ Supply current from $V_{CC}$	$V_{CC} = 5\text{ V},$	All inputs at 5, No load		30	mA

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## MULTIPLE RS-232 DRIVERS AND RECEIVERS

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### DRIVER SECTION

**electrical characteristics over recommended operating free-air temperature range,  $V_{DD} = 9\text{ V}$ ,  $V_{SS} = -9\text{ V}$ ,  $V_{CC} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{OH}$ High-level output voltage	$V_{IL} = 0.8\text{ V}$ , $R_L = 3\text{ k}\Omega$ , See Figure 1	6	7.5		V
$V_{OL}$ Low-level output voltage (see Note 3)	$V_{IH} = 1.9\text{ V}$ , $R_L = 3\text{ k}\Omega$ , See Figure 1		-7.5	-6	V
$I_{IH}$ High-level input current	$V_I = 5\text{ V}$ , See Figure 2			10	$\mu\text{A}$
$I_{IL}$ Low-level input current	$V_I = 0$ , See Figure 2			-1.6	mA
$I_{OS(H)}$ High-level short-circuit output current (see Note 4)	$V_{IL} = 0.8\text{ V}$ , $V_O = 0$ , See Figure 1	-4.5	-12	-19.5	mA
$I_{OS(L)}$ Low-level short-circuit output current	$V_{IH} = 2\text{ V}$ , $V_O = 0$ , See Figure 1	4.5	12	19.5	mA
$r_O$ Output resistance (see Note 5)	$V_{CC} = V_{DD} = V_{SS} = 0$ , $V_O = -2\text{ V to } 2\text{ V}$	300			$\Omega$

- NOTES: 3. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only (e.g., if  $-10\text{ V}$  is maximum, the typical value is a more negative voltage).
4. Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings.
5. Test conditions are those specified by TIA/EIA-232-F and as listed above.

**switching characteristics,  $V_{CC} = 5\text{ V}$ ,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$ ,  $T_A = 25^\circ\text{C}$**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$ Propagation delay time, low- to high-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$ , See Figure 3		315	500	ns
$t_{PHL}$ Propagation delay time, high- to low-level output			75	175	ns
$t_{TLH}$ Transition time, low- to high-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$ , See Figure 3		60	100	ns
	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 2500\text{ pF}$ , See Figure 3 and Note 6		1.7	2.5	$\mu\text{s}$
$t_{THL}$ Transition time, high- to low-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$ , See Figure 3		40	75	ns
	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 2500\text{ pF}$ , See Figure 3 and Note 6		1.5	2.5	$\mu\text{s}$

NOTE 6: Measured between  $\pm 3\text{-V}$  and  $\pm 3\text{-V}$  points of the output waveform (TIA/EIA-232-F conditions), all unused inputs are tied either high or low.

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## MULTIPLE RS-232 DRIVERS AND RECEIVERS

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### RECEIVER SECTION

**electrical characteristics over recommended operating conditions (unless otherwise noted)**

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V <sub>IT+</sub>	Positive-going input threshold voltage	See Figure 5	T <sub>A</sub> = 25°C	1.75	1.9	2.3	V
			T <sub>A</sub> = 0°C to 70 °C	1.55		2.3	
V <sub>IT−</sub>	Negative-going input threshold voltage			0.75	0.97	1.25	
V <sub>hys</sub>	Input hysteresis voltage (V <sub>IT+</sub> − V <sub>IT−</sub> )			0.5			
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = −0.5 mA	V <sub>IH</sub> = 0.75 V	2.6	4	5	V
			Inputs open	2.6			
V <sub>OL</sub>	Low-level input voltage	I <sub>OL</sub> = 10 mA,	V <sub>I</sub> = 3 V		0.2	0.45	V
I <sub>IH</sub>	High-level input current	V <sub>I</sub> = 25 V,	See Figure 5	3.6		8.3	mA
		V <sub>I</sub> = 3 V,	See Figure 5	0.43			
I <sub>IL</sub>	Low-level output current	V <sub>I</sub> = −25 V,	See Figure 5	−3.6		−8.3	mA
		V <sub>I</sub> = −3 V,	See Figure 5	−0.43			
I <sub>OS</sub>	Short-circuit output current	See Figure 4			−3.4	−12	mA

† All typical values are at  $T_A = 25^{\circ}\text{C}$ ,  $V_{CC} = 5\text{ V}$ ,  $V_{DD} = 9\text{ V}$ , and  $V_{SS} = -9\text{ V}$ .

**switching characteristics,  $V_{CC} = 5\text{ V}$ ,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$ ,  $T_A = 25^{\circ}\text{C}$**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$ Propagation delay time, low- to high-level output	$C_L = 50\text{ pF}, R_L = 5\text{ k}\Omega,$ See Figure 6		107	250	ns
$t_{PHL}$ Propagation delay time, high- to low-level output			42	150	ns
$t_{TLH}$ Transition time, low- to high-level output			175	350	ns
$t_{THL}$ Transition time, high- to low-level output			16	60	ns
$t_{PLH}$ Propagation delay time, low- to high-level output	$C_L = 15\text{ pF}, R_L = 1.5\text{ k}\Omega,$ See Figure 6		100	160	ns
$t_{PHL}$ Propagation delay time, high- to low-level output			60	100	ns
$t_{TLH}$ Transition time, low- to high-level output			90	175	ns
$t_{THL}$ Transition time, high- to low-level output			15	50	ns

### PARAMETER MEASUREMENT INFORMATION

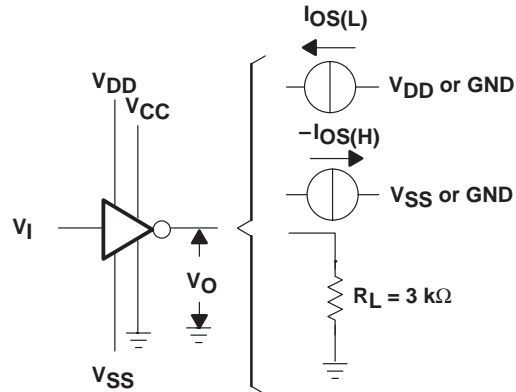


Figure 1. Driver Test Circuit for  $V_{OH}$ ,  $V_{OL}$ ,  $I_{OS(H)}$ , and  $I_{OS(L)}$

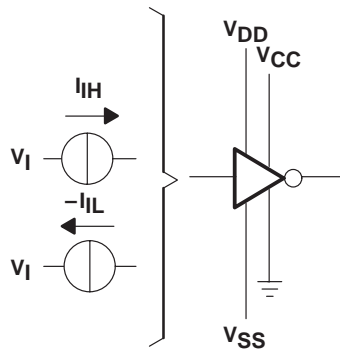
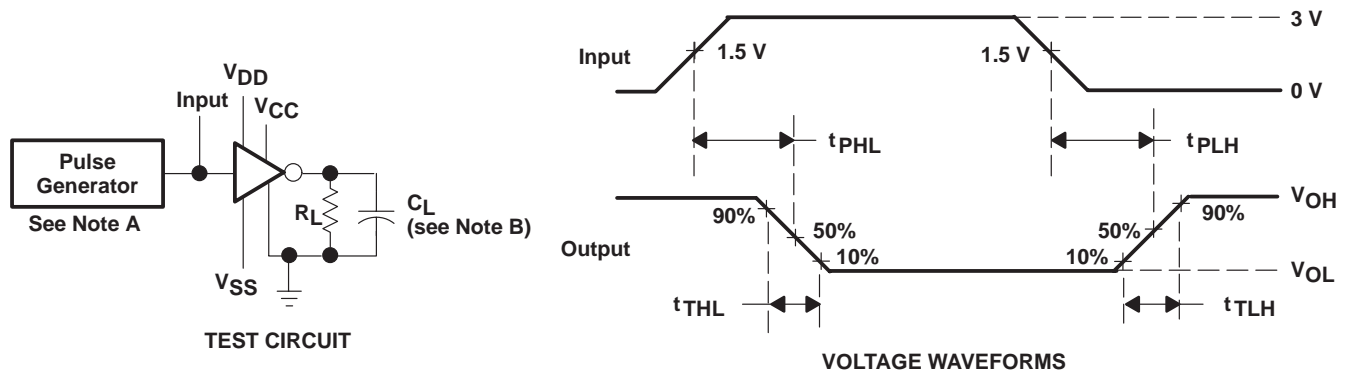


Figure 2. Driver Test Circuit for  $I_{IH}$  and  $I_{IL}$



- NOTES: A. The pulse generator has the following characteristics:  $t_W = 25\text{ }\mu\text{s}$ ,  $\text{PRR} = 20\text{ kHz}$ ,  $Z_O = 50\text{ }\Omega$ ,  $t_r = t_f < 50\text{ ns}$ .  
B.  $C_L$  includes probe and jig capacitance.

Figure 3. Driver Test Circuit and Voltage Waveforms

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### PARAMETER MEASUREMENT INFORMATION

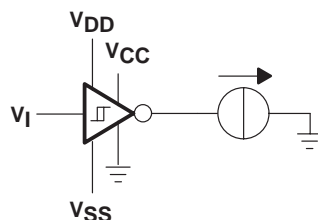


Figure 4. Receiver Test Circuit for  $I_{OS}$

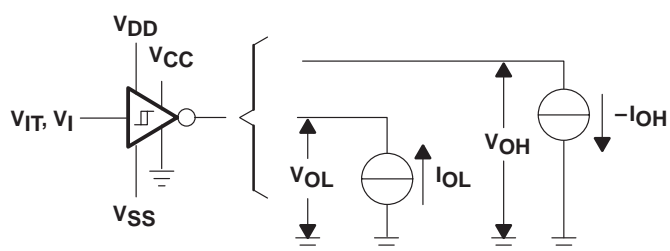
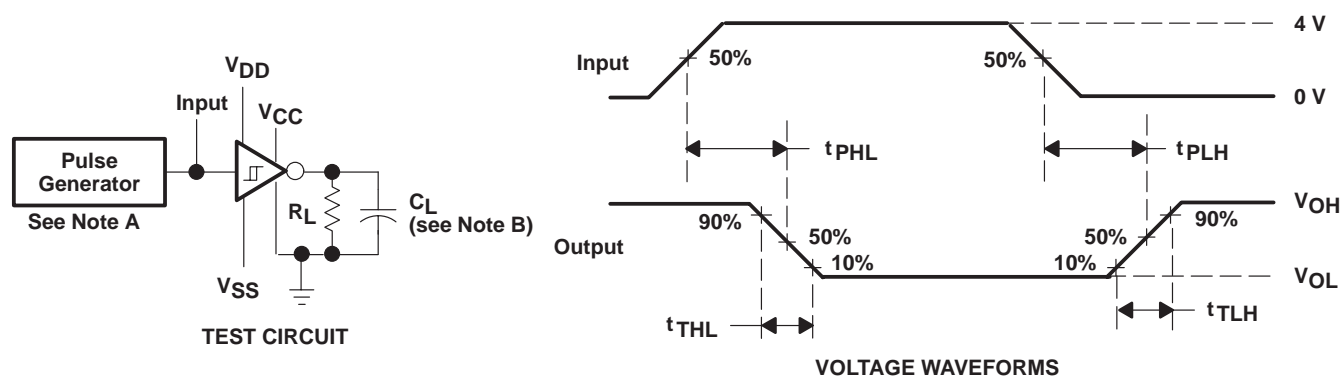


Figure 5. Receiver Test Circuit for  $V_{IT}$ ,  $V_{OH}$ , and  $V_{OL}$



- NOTES: A. The pulse generator has the following characteristics:  $t_W = 25 \mu s$ ,  $PRR = 20 \text{ kHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r = t_f < 50 \text{ ns}$ .  
 B.  $C_L$  includes probe and jig capacitance.

Figure 6. Receiver Propagation and Transition Times



TYPICAL CHARACTERISTICS

DRIVER SECTION

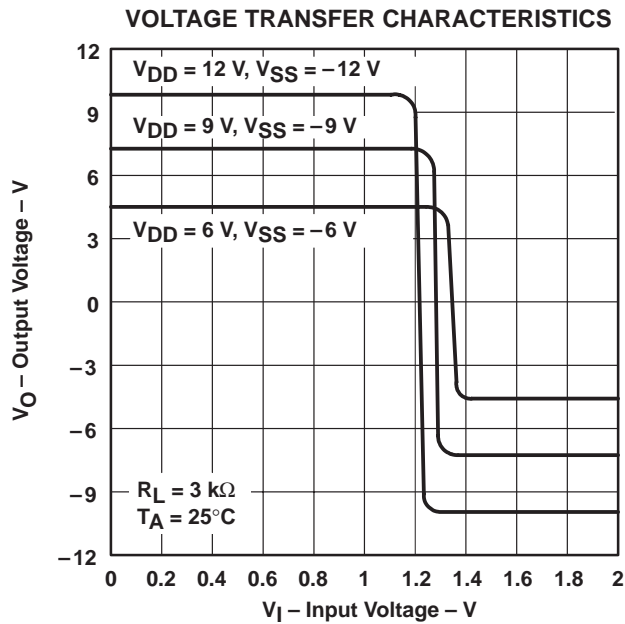


Figure 7

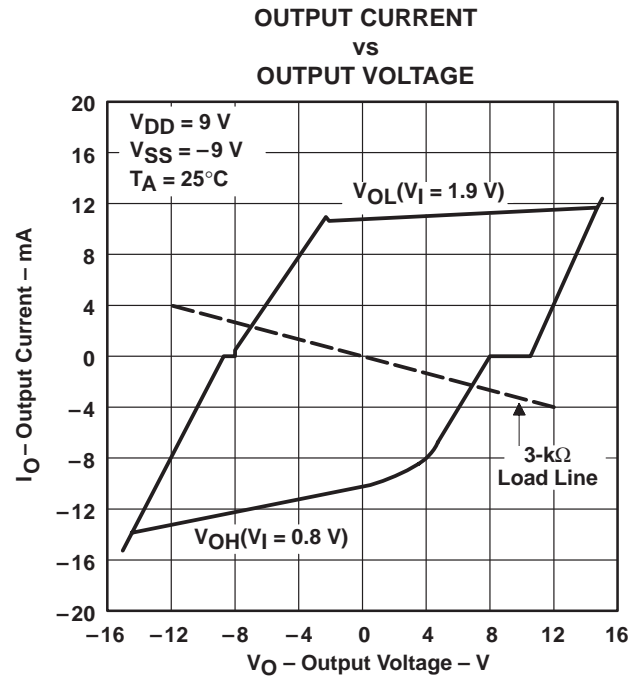


Figure 8

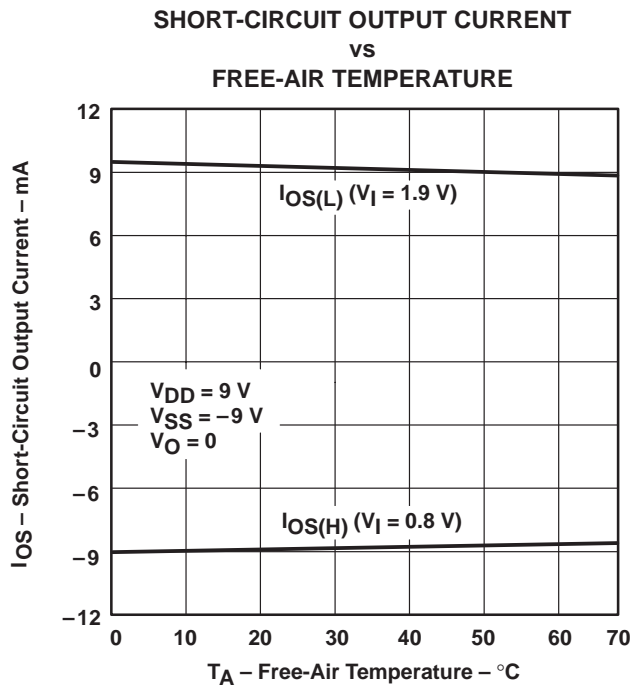


Figure 9

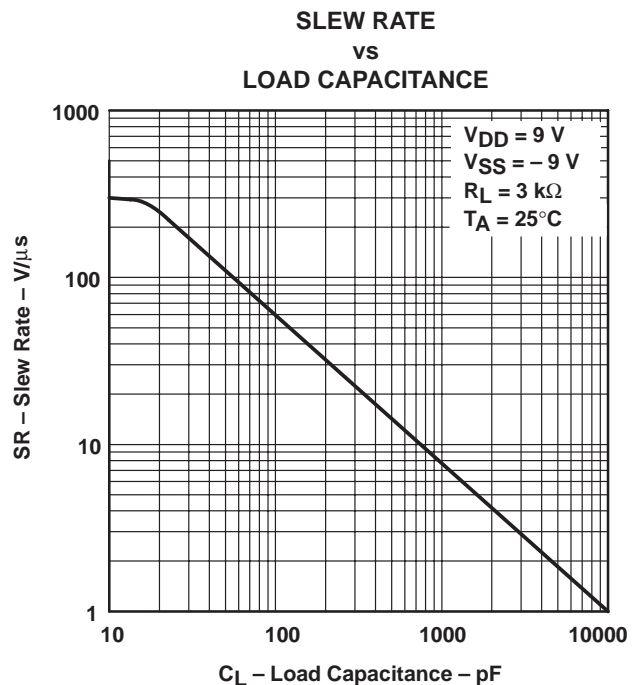


Figure 10

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TYPICAL CHARACTERISTICS

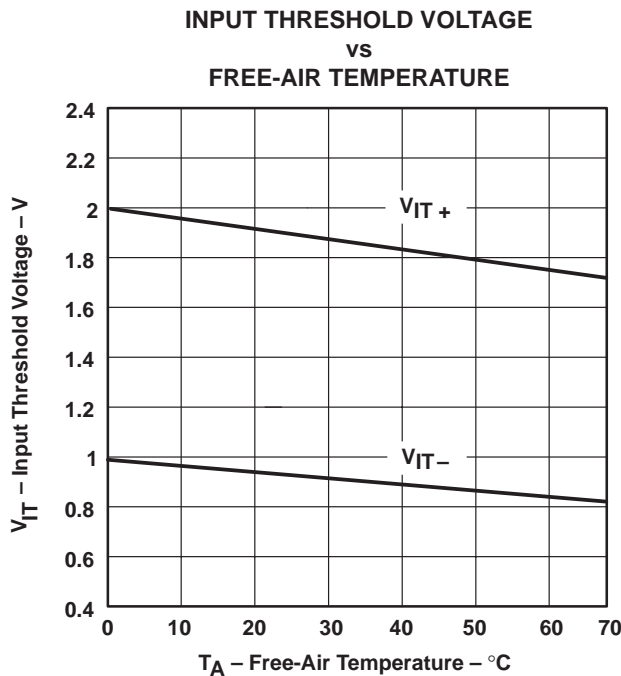


Figure 11

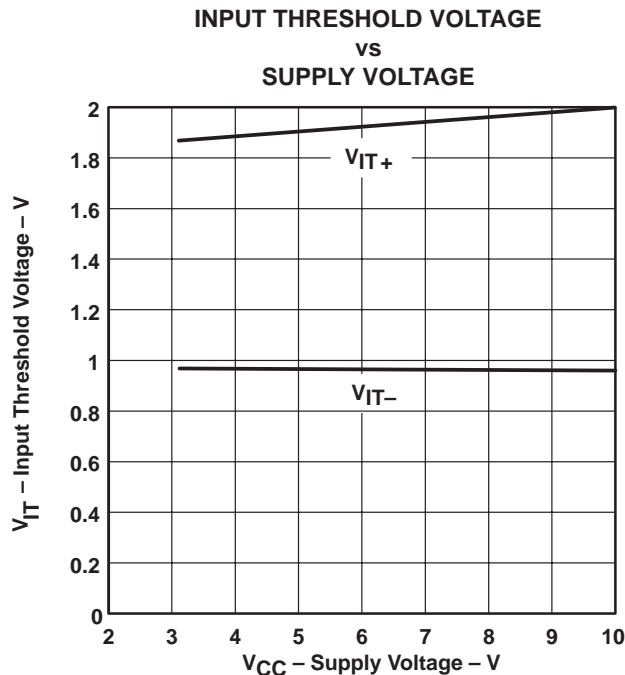
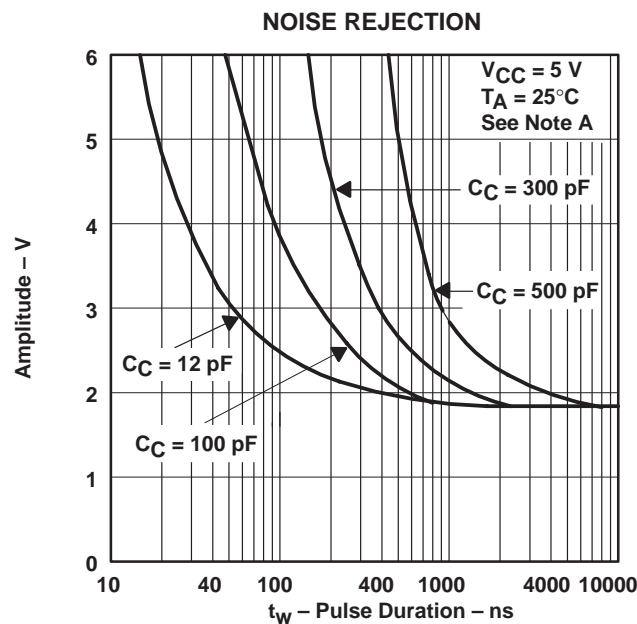


Figure 12



NOTE A: This figure shows the maximum amplitude of a positive-going pulse that, starting from 0 V, does not cause a change of the output level.

Figure 13

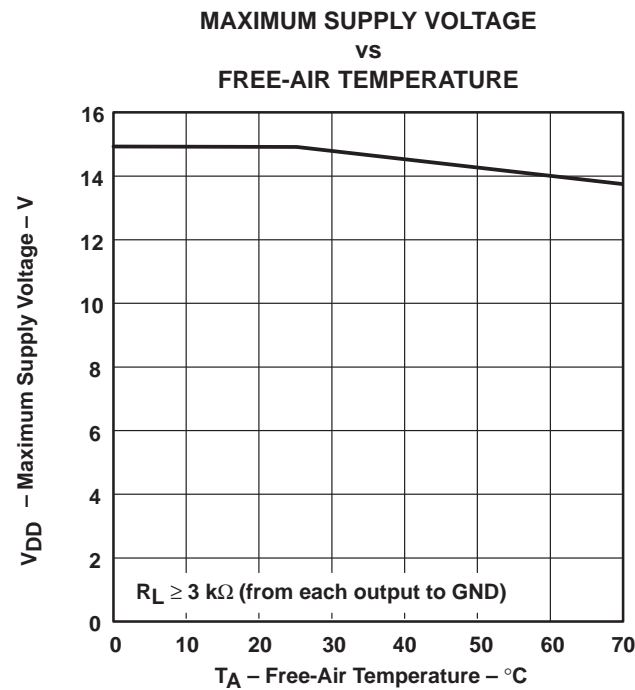
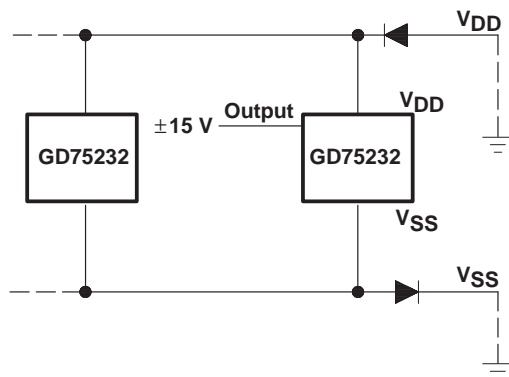


Figure 14

Diodes placed in series with the  $V_{DD}$  and  $V_{SS}$  leads protect the GD75232 in the fault condition in which the device outputs are shorted to  $\pm 15$  V and the power supplies are at low and provide low-impedance paths to ground (see Figure 15).



The diagram shows the GD75232 transceiver chip connected to a TL16C450 ACE and a TIA/EIA-232-F DB9S Connector. The chip has pins for GND, VCC, VSS, and VDD. It has 19 pins on the left for the TL16C450 ACE (RI, DTR, CTS, SO, RTS, SI, DSR, DCD) and 10 pins on the right for the TIA/EIA-232-F DB9S Connector (RI, DTR, CTS, TX, RTS, RX, DSR, DCD). The chip is labeled GD75232. Power is supplied by a 5V source to VCC and a -12V source to VSS. Signal lines are connected between the chip pins and the external devices. Capacitors C1, C2, and C3 are shown connected to the RX, RTS, and CTS pins respectively.



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